

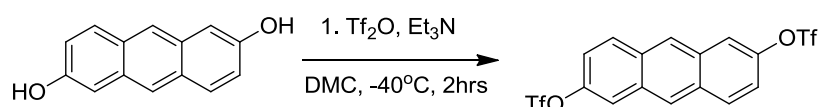
## Supporting Information

### Oligofuran-Containing Molecules for Organic Electronics

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#### Synthetic Procedure

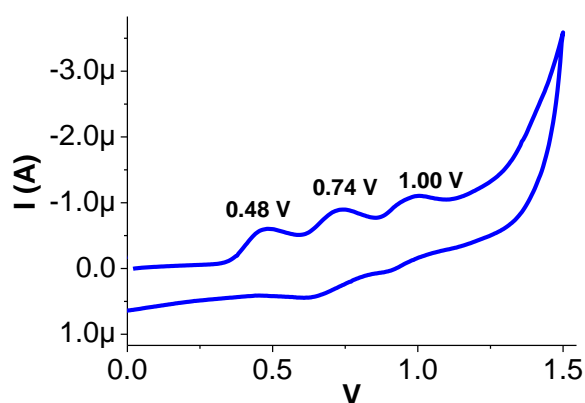


**2,6-bis(trifluoromethanesulfonyloxy)anthracene (3)** The synthetic procedure is similar to that previously reported.<sup>1</sup> To 50 mL two neck round bottom flask fitted with magnetic bar, thermometer and nitrogen inlet was added 2,6-dihydroxyanthracene (0.13 g, 0.62 mmol), dry dichloromethane (10 mL) and triethylamine (0.59 g, 5.86 mmol). After cooling down to -40°C (acetonitrile/dry ice), triflic anhydride (0.44 g, 1.56 mmol) was slowly added dropwise via syringe. The reaction mixture was stirred for 2 hours at -40°C and the cooling bath was removed to allow warming up to room temperature. Dichloromethane (20 mL) was added and the resulted solution was washed with water (50 mL). The organic layer was separated, dried over MgSO<sub>4</sub> and the evaporated under reduced pressure to afford brownish solid. The crude product was purified by column chromatography (silica, hexane/EtOAc) to afford white solid (0.29 g, 85 %). Spectroscopic data are in good agreement with literature data. (Mery,S.; Haristoy, D.; Nicoud, J.-F.; Guillon, D.; Monobeb, H.; Shimizub, Y. *J. Mater. Chem.* **2003**, 13, 1622–1630).

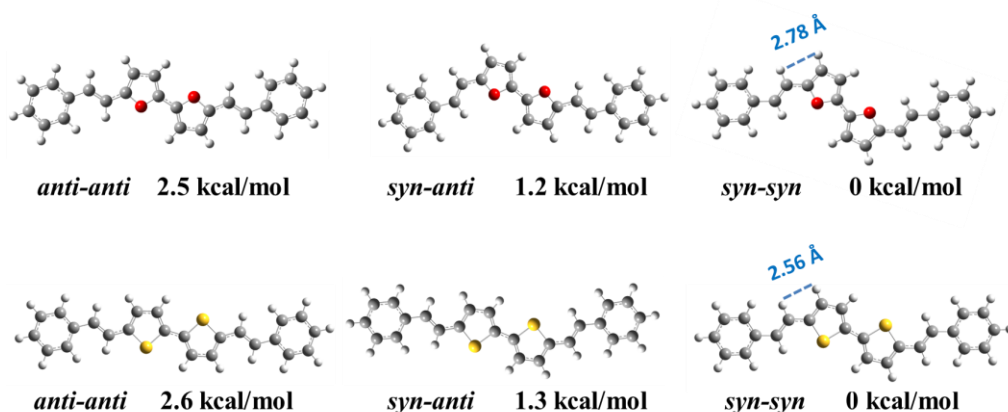
#### X-ray structural analysis of DHS-2F (CCDC reference number 905238).

Compound **DHS-2F** was crystallized from hexane to give yellow needles. Crystal data: C<sub>36</sub>H<sub>42</sub>O<sub>2</sub>, 0.24 × 0.02 × 0.02 mm<sup>3</sup>, triclinic, *PI*, a = 5.4160(4)Å, b =

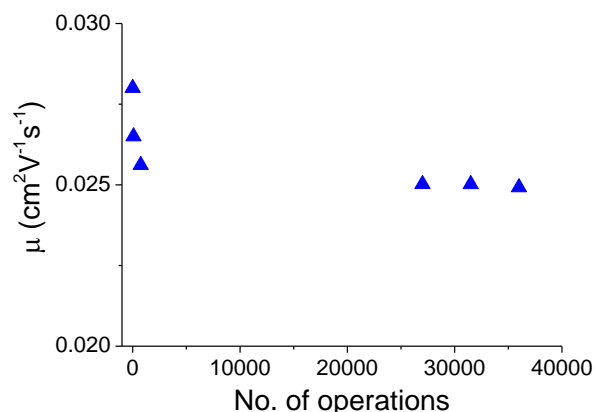
16.0287(12) Å,  $c = 18.6890(18)$  Å,  $\alpha = 155.342(2)^\circ$   $\beta = 91.826(4)^\circ$   $\gamma = 94.608(3)^\circ$  from 9796 reflections,  $T = 100(2)$  K,  $V = 1457.6(2)$  Å<sup>3</sup>,  $Z = 2$ ,  $F_w = 506.70$ ,  $D_c = 1.154$  Mg.m<sup>-3</sup>,  $\mu = 0.069$  mm<sup>-1</sup>. *Data collection and processing:* Bruker KappaAPEXII diffractometer, MoK $\alpha$  ( $\lambda = 0.71073$  Å), graphite monochromator, MiraCol optics,  $-6 \leq h \leq 6$ ,  $-19 \leq k \leq 19$ ,  $-22 \leq l \leq 22$ ,  $2\theta_{\max} = 52.22^\circ$ , frame scan width =  $0.5^\circ$ , scan speed  $1.0^\circ$  per 240 s, typical peak mosaicity  $0.6^\circ$ , 22005 reflections collected, 9796 independent reflections ( $R_{\text{int}} = 0.035$ ). The data were processed with Bruker Apex2. *Solution and refinement:* Structure solved with Bruker Shelxs. Full matrix least-squares refinement based on  $F^2$  SHELXL-97, 689 parameters with 3 restraints gave final  $R_1 = 0.0442$  (based on  $F^2$ ) for data with  $I > 2\sigma(I)$  and  $R_1 = 0.0726$  on 9796 reflections, goodness-of-fit on  $F^2 = 1.005$ , largest electron density peak =  $0.181\text{e}/\text{Å}^3$  and hole  $-0.211\text{e}/\text{Å}^3$ .



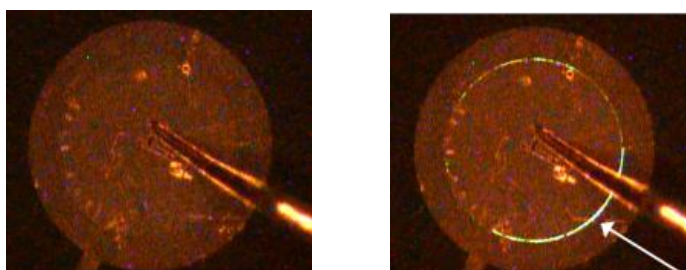
**Figure S1.** Cyclic voltammogram of **DH2F-Ant** vs. SCE in dichloroethane with 0.1M  $\text{Bu}_4\text{N}^+\text{BF}_4$ , measured at scan rates of  $50\text{ mV s}^{-1}$ .



**Figure S2.** Calculated (B3LY/6-31G(d)) geometries and corresponding energies (in kcal/mol vs. *syn-syn* conformation) of different conformations of **DS-2F** (top) and **DS-2T** (bottom).



**Figure S3.** Bias stress measurements of FETs of **DH-7F** on Si/SiO<sub>2</sub>/PMMA, (each operation presents a sweep of V<sub>G</sub> from 0 to -75 V, keeping V<sub>DS</sub> = -75 V).



**Figure S4.** Electroluminescence of a bottom-contact OFET based on **DH-7F** under external illumination. The left image shows the device without applying bias, and the right image shows electroluminescence appearing in the vicinity of the cathode upon biasing of the gated device (indicated by the white arrow).

**Table S1.** Absolute energies (Hartrees) for calculated structures.

Compound Name	Energy (HF)	Compound Name	Energy (HF)
<b>DS-2F</b> ( <i>syn-syn</i> )	-1075.80195341	<b>DS-2T</b> ( <i>syn-syn</i> )	-1721.74878460
<b>DS-2F</b> ( <i>syn-anti</i> )	-1075.79998497	<b>DS-2T</b> ( <i>syn-anti</i> )	-1721.74667006
<b>DS-2F</b> ( <i>anti-anti</i> )	-1075.79790707	<b>DS-2T</b> ( <i>anti-anti</i> )	-1721.74465133
<b>DS-4F</b> ( <i>anti-anti</i> )	-1533.47872489	<b>DS-4T</b> ( <i>anti-anti</i> )	-2825.37519366
<b>D2F-Ant</b>	-1454.88441998	<b>D2T-Ant</b>	-2746.78687140

1 Y. Goto, K. Nakajima, N. Mizoshita, M. Suda, N. Tanaka, T. Hasegawa, T. Shimada, T. Tani and S. Inagaki, *Microporous Mesoporous Mater.*, 2009, **117**, 535-540.